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FDD3N50NZ N-Channel UniFETTM II MOSFET 500 V, 2.5 A, 2.5 Ω

Features

- $R_{DS(on)} = 2.1 \Omega (Typ.) @ V_{GS} = 10 V, I_D = 1.25 A$
- Low Gate Charge (Typ. 6.2 nC)
- Low C_{rss} (Typ. 2.5 pF)
- 100% Avalanche Tested
- Improved dv/dt Capability
- ESD Imoroved Capability
- RoHS Compliant

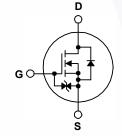
Applications

- LCD/LED/PDP TV
- Lighting
- Uninterruptible Power Supply

G S D-PAK



UniFETTM II MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on advanced planar stripe and DMOS technology. This advanced MOSFET family has the smallest on-state resistance among the planar MOSFET, and also provides superior switching performance and higher avalanche energy strength. In addition, internal gate-source ESD diode allows UniFET II MOSFET to withstand over 2kV HBM surge stress. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp balasts.



Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FDD3N50NZTM	Unit		
V _{DSS}	Drain to Source Voltage			500	V	
V _{GSS}	Gate to Source Voltage			±25	V	
I _D	Drain Current	- Continuous (T _C = 25 ^o C)		2.5	•	
	Drain Current	- Continuous (T _C = 100 ^o C)		1.5	— A	
I _{DM}	Drain Current	- Pulsed (N	Note 1)	10	А	
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		lote 2)	114	mJ	
I _{AR}	Avalanche Current (Note 1)		Note 1)	2.5	А	
E _{AR}	Repetitive Avalanche Energy (Note 1)		Note 1)	4	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		Note 3)	10	V/ns	
P _D	Dewer Dissignation	(T _C = 25°C)		40	W	
	Power Dissipation	- Derate Above 25°C		0.3	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
T	Maximum Lead Temperature	for Soldering, 1/8" from Case for 5 Se	econds	300	°C	

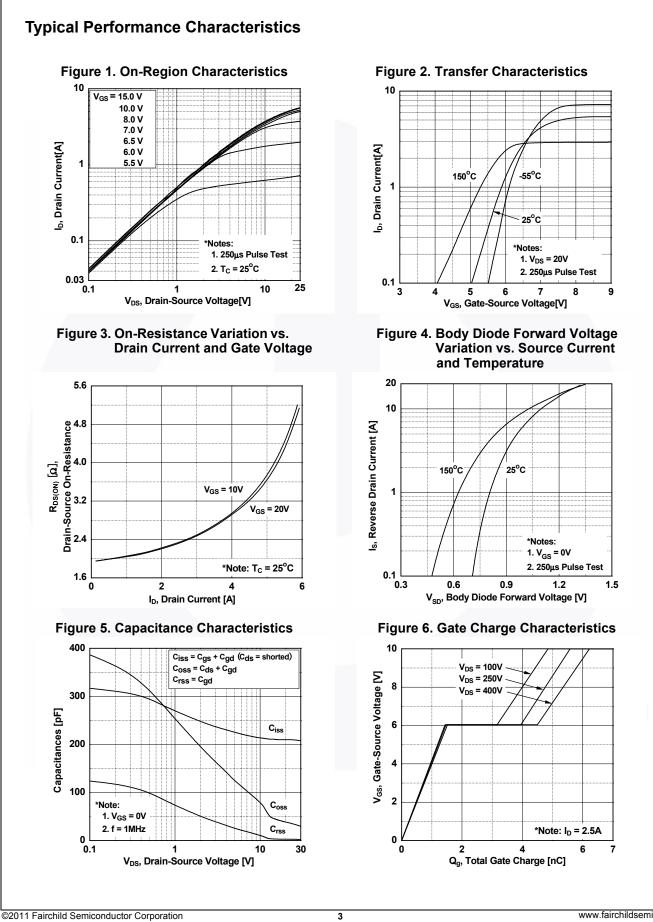
Thermal Characteristics

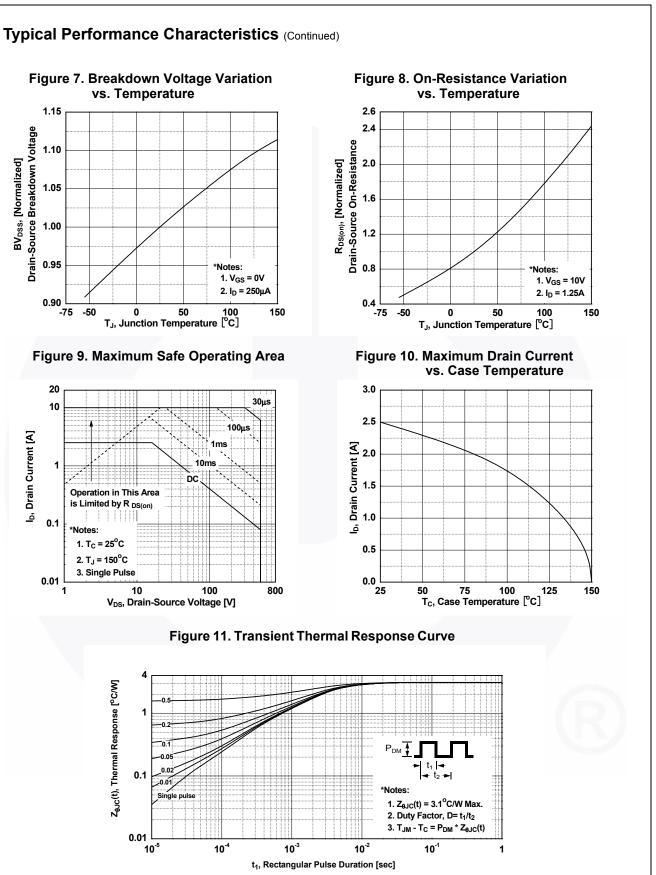
Symbol	Parameter	FDD3N50NZTM	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case, Max.	3.1	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient, Max.	90	0/11

November 2013

		Package	Packing Method	Reel Size	e Ta	ape Width	Qu	antity	
		DPAK			-		2500 units		
Electric	al Chara	acteristics T _c = 25°C	unless othe	rwise noted.					
Symbol		Parameter		Test Condition	S	Min.	Тур.	Max.	Unit
Off Chara	cteristics				L. L. L.				1
BV _{DSS}	Drain to	Source Breakdown Voltage		$= 250 \mu A V_{cs} = 0 V T$	$c = 25^{\circ}C$	500	-	-	V
ΔBV_{DSS}		wn Voltage Temperature		$I_D = 250 \ \mu\text{A}, V_{GS} = 0 \ V, T_C = 25^{\circ}\text{C}$ $I_D = 250 \ \mu\text{A}, \text{Referenced to } 25^{\circ}\text{C}$		000			
$/\Delta T_J$	Coefficie		I _D =			-	0.5	-	V/°C
1	Zoro Cot	te Voltage Drain Current	VD	V _{DS} = 500 V, V _{GS} = 0 V		-	-	1	
I _{DSS}	Zelo Gal	e voltage Drain Current	V _D :	_S = 400 V, V _{GS} = 0 V,1	_C = 125 ^o C	-	-	10	μΑ
I _{GSS}	Gate to E	Body Leakage Current	V _G	_S = ±25 V, V _{DS} = 0 V		-	-	±10	μA
On Chara	cteristics	i							
V _{GS(th)}	Gate Thr	reshold Voltage	VG	_S = V _{DS} , I _D = 250 μA		3.0	-	5.0	V
R _{DS(on)}		ain to Source On Resistand		_S = 10 V, I _D = 1.25 A		-	2.1	2.5	Ω
9 _{FS}	Forward	Transconductance		_S = 20 V, I _D = 1.25 A		-	1.9	-	S
Dynamic	Characte	ristics	ł				<u>н</u> – н		
C _{iss}		pacitance				-	210	280	pF
C _{oss}		apacitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz		-	30	45	pF
C _{rss}		Transfer Capacitance	t =			-	2.5	5	pF
Q _{g(tot)}		te Charge at 10V	V-	V _{DS} = 400 V, I _D = 2.5 A, V _{GS} = 10 V (Note 4)		-	6.2	8	nC
Q _{gs}		Source Gate Charge				-	1.4	-	nC
Q _{gd}		Drain "Miller" Charge	0			-	3.1	-	nC
Switching	Charact	eristics	I						_
t _{d(on)}		Delay Time					10	30	ns
t _r		Rise Time	VD	V_{DD} = 250 V, I _D = 2.5 A, V_{GS} = 10 V, R _G = 25 Ω (Note 4)		-	15	40	ns
t _{d(off)}		Delay Time	V _G			-	26	60	ns
t _f		Fall Time				/	17	45	ns
	urce Died	e Characteristics			(,				
I _s		n Continuous Drain to Sour	ce Diode Fo	rward Current			-	2.5	А
I _{SM}	Maximum Pulsed Drain to Source Diod					-	-	10	A
V _{SD}		Source Diode Forward Volta	t			-	-	1.4	V
t _{rr}		Recovery Time		$V_{GS} = 0 V, I_{SD} = 2.5 A,$ $U_{GS} = 0 V, I_{SD} = 2.5 A,$ $dI_{F}/dt = 100 A/\mu s$		-	190	-	ns
Q _{rr}		Recovery Charge				-	0.52	· -	μC

3. $I_{SD} \le 2.5$ A, di/dt ≤ 200 A/µs, $V_{DD} \le BV_{DSS}$, starting T_J = 25°C. 4. Essentially independent of operating temperature typical characteristics.





1.15

1.10

1.05

1.00

0.95

0.90

20

10

1

0.1

0.01

1

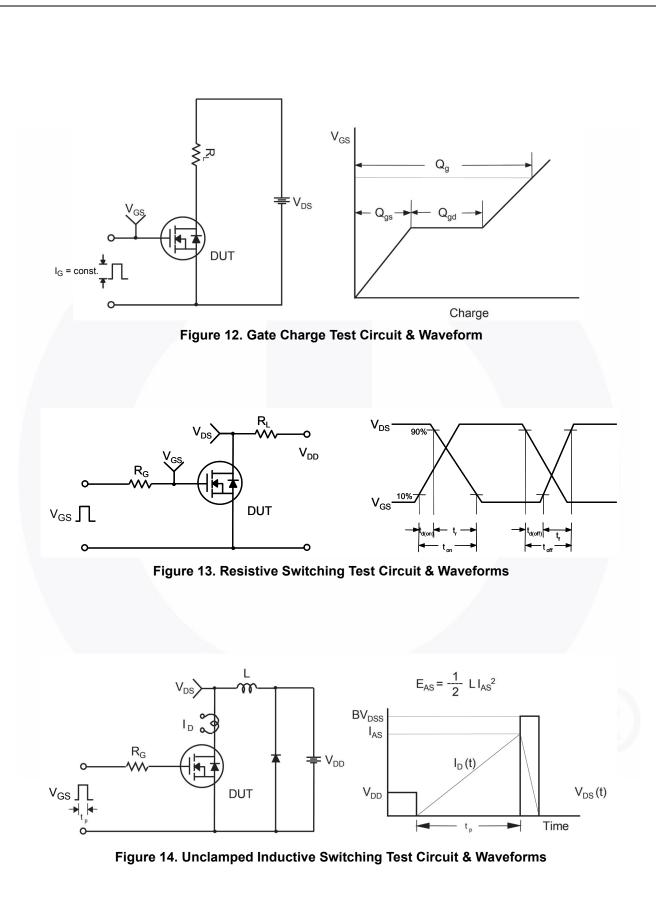
*Notes:

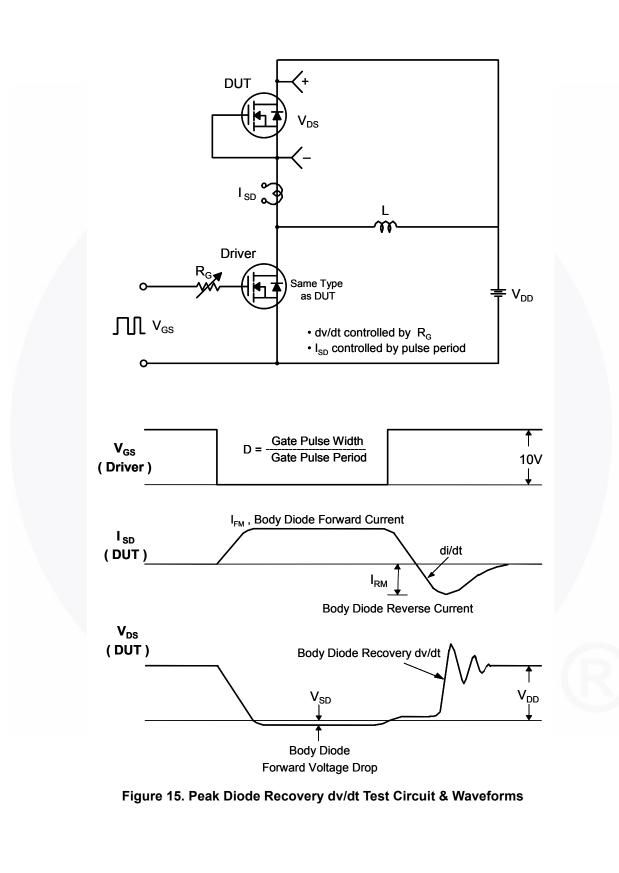
l_b, Drain Current [A]

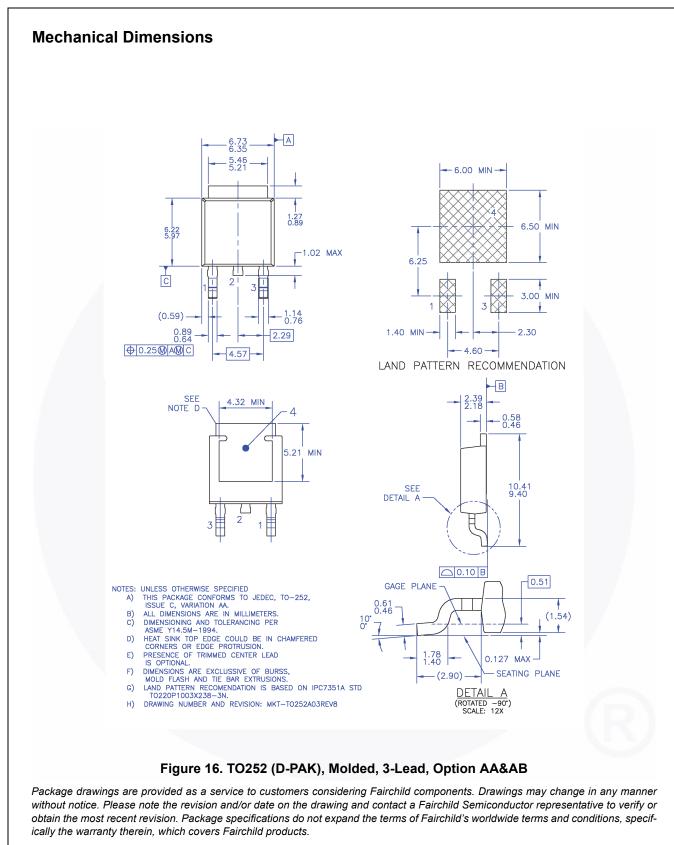
-75 -50

Drain-Source Breakdown Voltage

BV_{DSS}, [Normalized]







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